## NSN 5961-01-151-6573

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-151-6573 **Inclosure Material:** Ceramic and metal **Overall Length:** 0.185 inches **Terminal Length:** 0.975 inches **Overall Diameter:** 0.130 inches **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 10.00 microamperes forward current, average peak **Power Rating Per Characteristic:** 12.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 ribbon Shelf Life: N/a **Unit Of Measure:** Demilitarization:

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